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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Gurtej Singh Sandhu et al.

Examiner: Unknown

Serial No.:

Unknown

Group Art Unit: Unknown

Filed:

Herewith

Docket: 303.676US3

Title:

CHEMICAL VAPOR DEPOSITION OF TITANIUM

PRELIMINARY AMENDMENT

Commissioner for Patents Washington, D.C. 20231

When the above-identified patent application is taken up for consideration, please amend the application as follows:

IN THE SPECIFICATION

Please make the paragraph substitutions indicated in the appendix entitled Clean Version of Amended Specification Paragraph. The specific changes incorporated in the substitute paragraph are shown in the following marked-up version of the original paragraph:

The paragraph beginning on page 1, line 4 is amended as follows:

This application is a <u>Divisional of U.S. Application No. 09/489,187</u>, filed on January 20, 2000, which is a continuation-in-part of U.S. Application Serial No. 09/030,705, filed February 25, 1998, now issued as U.S. Patent 6,143,362 on November 7, 2000, which is hereby incorporated by reference in its entirety.

IN THE CLAIMS

Please cancel claims 1-45 and 48-56 after adding the following new claims.

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(New) A memory device, comprising:

a semiconductor substrate;

a memory array coupled to the semiconductor substrate;

a control circuit, operatively coupled to the memory array;

an I/O circuit, operatively coupled to the memory array;

an electronic device coupled to the semiconductor substrate, the electronic device having